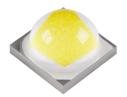
Superior Efficacy & Lumen output with Small Form Factor

Z Power LED - Z5-M4









Product Brief

Description

- The Z-Power series is designed for high flux output applications with high current operation capability.
- It incorporates state of the art SMD design and low thermal resistant material.
- The Z Power LED is ideal light sources for directional lighting applications such as Spot Lights, various outdoor applications, automotive lightings and high performance torches.

Features and Benefits

- High Lumen Output and Efficacy
- Designed for high current operation
- Low Thermal Resistance
- ANSI compliant Binning
- Ceramic package

Key Applications

- Architectural
- Industrial
- · Outdoor area
- Exterior Lighting
- Commercial

Rev1.2 Nov. 2024 www.seoulsemicon.com



Table of Contents

Inde	ex	
•	Product Brief	1
•	Table of Contents	2
•	Performance Characteristics	3
•	Characteristics Graph	5
•	Color Bin Structure	10
•	Mixing order kiting combination	17
•	Product Nomenclature	18
•	Mechanical Dimensions	21
•	Recommended Solder Pad	22
•	Reflow Soldering Characteristics	23
•	Emitter Tape & Reel Packaging	24
•	Packing Information	25
•	Handling of Silicone Resin for LEDs	26
•	Precaution For Use	27
•	Company Information	30

Rev1.2 Nov. 2024 **2** www.seoulsemicon.com



Performance Characteristics

Table 1.Product Selection Guide, I_F =700mA, T_j =85°C

CRI CCT		Performance	Flux & Im/W(Typ.) IF=700mA
Min	661	renormance	Flux & III/W(1yp.) IF=700IIIA
	6500K	Flux	363
	03001	lm/W	185
	5700K	Flux	366
	370010	lm/W	187
	5000K	Flux	368
	300010	lm/W	188
	4000K	Flux	371
70	400010	lm/W	189
70	3500K	Flux	367
	330010	lm/W	187
	3000K	Flux	346
	300010	lm/W	176
	2700K	Flux	334
	270010	lm/W	170
	2200K	Flux	300
	22001	lm/W	153
	6500K	Flux	336
	0300K	lm/W	171
	5700K -	Flux	338
		lm/W	172
		Flux	343
		lm/W	175
80	4000K	Flux	343
00	4000K	lm/W	175
	3500K	Flux	339
	3500K	lm/W	173
	20001/	Flux	318
	3000K	lm/W	162
	2700K	Flux	309
	2700K	lm/W	158
	65001/	Flux	301
	6500K	lm/W	154
	5700V	Flux	303
	5700K	lm/W	155
	5000K	Flux	305
	5000K	lm/W	156
00	4000K	Flux	307
90	40001	lm/W	157
	35001/	Flux	304
	3500K	lm/W	155
	200014	Flux	287
	3000K	lm/W	147
	27001/	Flux	277
	2700K	lm/W	141

Notes:

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements
- (3) Typ lumen table is only for reference .

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Performance Characteristics

Table 2. Characteristics

Parameter	Symbol	Value			Unit
Falanietei	Symbol	Min.	Тур.	Max. [4]	Offic
Forward Current	l _F	-	700	2000 [1]	mA
Peak Pulsed Forward Current [2]	l _F			2600	mA
Forward Voltage (@700mA, 85°C)	V_{F}	-	-	3.00	V
Junction Temperature	T_j	-	-	150	°C
Operating Temperature	T_{op}	-40	-	105	°C
Storage Temperature	T_{stg}	-40	-	125	°C
Viewing angle	θ		120		degree
Thermal resistance (J to S) [3]	$R\theta_{J-S}$	-	3	-	K/W
ESD Sensitivity(HBM)		Class 3	B JEDEC JS-0	01-2017	

Notes:

(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.

- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.
- (5) Tolerance is $\pm 0.06 \text{V}$ on forward voltage measurements.
- (6) $R\theta_{J-S}$ is tested at 700mA.
- · It is recommended to use it in the condition that the reliability is secured within the Max value.
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.

Rev1.2 Nov. 2024 4 www.seoulsemicon.com

Fig 1. Color Spectrum

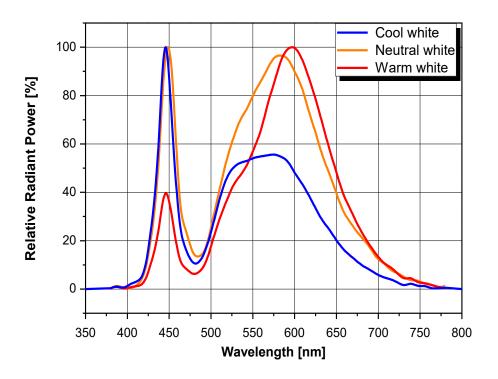
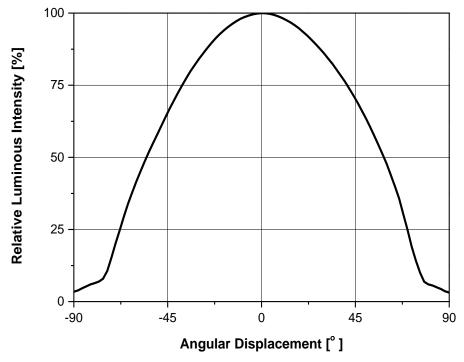


Fig 2. Typical Spatial Distribution



Using less than 100mA is not recommended

Fig 3. Forward Voltage vs. Forward Current, T_i=85°C

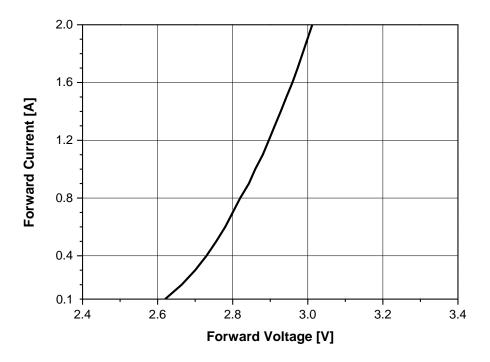
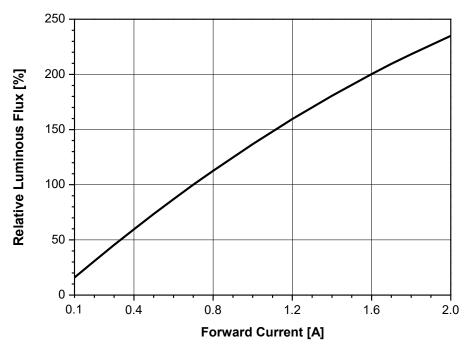


Fig 4. Forward Current vs. Relative Luminous Flux, T_i=85°C



· Using less than 100mA is not recommended

Rev1.2 Nov. 2024 6 www.seoulsemicon.com

Fig 5. Forward Current vs. CIE X, Y Shift, T_i=85°C

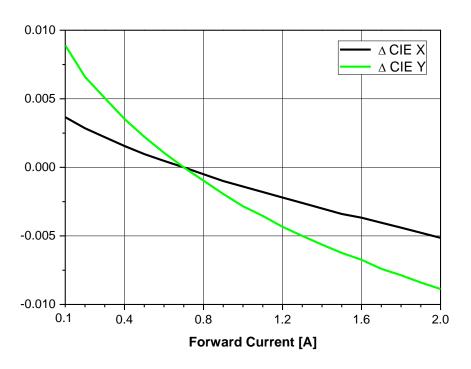
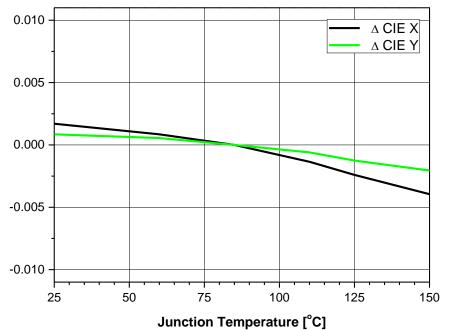


Fig 6. Junction Temp. vs. CIE X, Y Shift, I_F=700mA



Using less than 100mA is not recommended



Fig 7. Relative Light Output vs. Junction Temperature, I_F=700mA

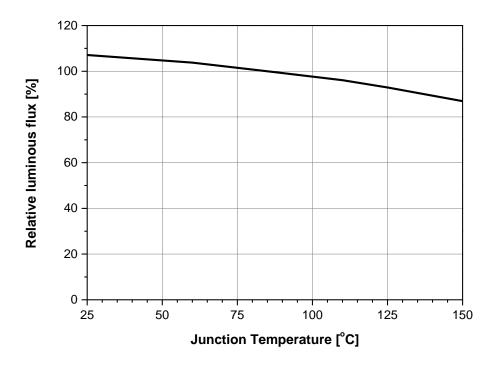
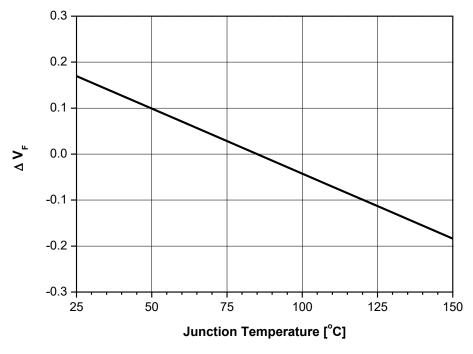


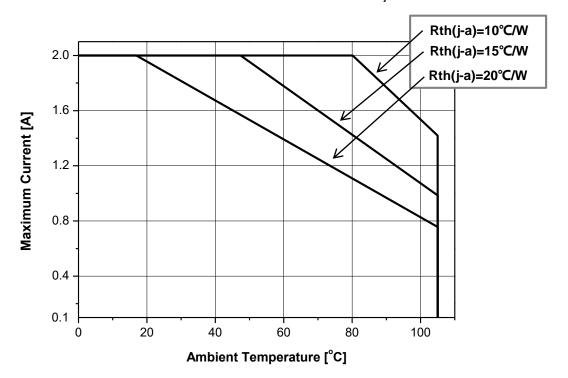
Fig 8. Relative Forward Voltage vs. Junction Temperature, I_F=700mA



Using less than 100mA is not recommended

Rev1.2 Nov. 2024 8 www.seoulsemicon.com

Fig 9. Maximum Forward Current vs. Ambient Temperature, T_i(max.)=150°C



Rev1.2 Nov. 2024 9 www.seoulsemicon.com

Using less than 100mA is not recommended



Table 3. Bin Code description, I_F=700mA, T_i=85°C

Luminous Flux [lm]					
Bin Code	Min.	Max.			
250	250	265			
265	265	280			
280	280	295			
295	295	310			
310	310	325			
325	325	340			
340	340	355			
355	355	370			
370	370	385			

Forward Voltage (V)					
Bin Code	Min.	Max.			
290	2.75	2.90			
300	2.90	3.00			

Notes:

- (1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
 - Color coordinate : $\pm 0.005,~CCT~\pm 5\%$ tolerance.
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.
- (5) Tolerance is $\pm 0.06 \mbox{V}$ on forward voltage measurements.

Rev1.2 Nov. 2024 10 www.seoulsemicon.com



Table 4. Flux Bin Distribution

Available Bin

CRI	CCT	Model	CIE					Flux	Bin				
	6000 ~ 7000K	E1	Α	235	250	265	280	295	310	325	340	355	370
	5300 ~ 6000K	E1	В	235	250	265	280	295	310	325	340	355	370
	4700 ~ 5300K	E1	С	235	250	265	280	295	310	325	340	355	370
70	3700 ~ 4200K	E1	Е	235	250	265	280	295	310	325	340	355	370
10	3200 ~ 3700K	E1	F	235	250	265	280	295	310	325	340	355	370
	2900 ~ 3200K	E1	G	235	250	265	280	295	310	325	340	355	370
	2600 ~ 2900K	E1	Н	235	250	265	280	295	310	325	340	355	370
	2300 ~ 2100K	E1	K	235	250	265	280	295	310	325	340	355	370
	6000 ~ 7000K	E1	Α	235	250	265	280	295	310	325	340	355	370
	5300 ~ 6000K	E1	В	235	250	265	280	295	310	325	340	355	370
	4700 ~ 5300K	E1	С	235	250	265	280	295	310	325	340	355	370
80	3700 ~ 4200K	E1	Е	235	250	265	280	295	310	325	340	355	370
	3200 ~ 3700K	E1	F	235	250	265	280	295	310	325	340	355	370
	2900 ~ 3200K	E1	G	235	250	265	280	295	310	325	340	355	370
	2600 ~ 2900K	E1	Н	235	250	265	280	295	310	325	340	355	370
	6000 ~ 7000K	E1	Α	235	250	265	280	295	310	325	340	355	370
	5300 ~ 6000K	E1	В	235	250	265	280	295	310	325	340	355	370
	4700 ~ 5300K	E1	С	235	250	265	280	295	310	325	340	355	370
90	3700 ~ 4200K	E1	Е	235	250	265	280	295	310	325	340	355	370
	3200 ~ 3700K	E1	F	235	250	265	280	295	310	325	340	355	370
	2900 ~ 3200K	E1	G	235	250	265	280	295	310	325	340	355	370
	2600 ~ 2900K	E1	Н	235	250	265	280	295	310	325	340	355	370

Notes:

(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.

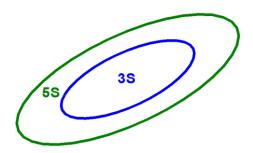
Color coordinate : $\pm 0.005,\ CCT\ \pm 5\%$ tolerance.

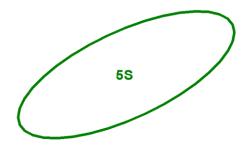
- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_{V} is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.
- (5) Tolerance is $\pm 0.06 V$ on forward voltage measurements.

Rev1.2 Nov. 2024 11 www.seoulsemicon.com



CIE Chromaticity Diagram T_i=85°C, I_F=700mA





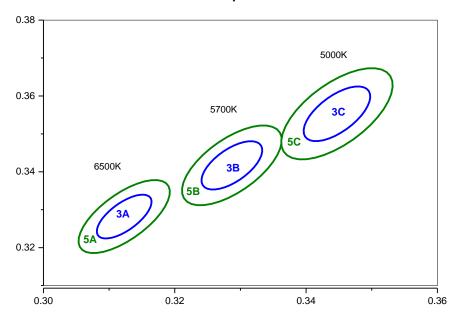
Order	Box Packing Method
xx3S	3S(3step) Single
xx4M	3S(3step) Single or 3S+5S Mixing

Order	Box Packing Method
xx5S	5S(5step) Single

Notes:

- 1. xx3S Order will ship 3S only
- 2. xx5S Order will ship 5S (=also include 3S)
- 3. xx4M Order will ship 3S & 5S Mixing(=also include 3S)
- 4. Doughnut Bin will not ship alone(=Will ship with mixing bin)
- * 'xx' can be 65=6500K, 56=5600K, 50=5000K, 40=4000K, 30=3000K, 27= 2700K,22=2200K

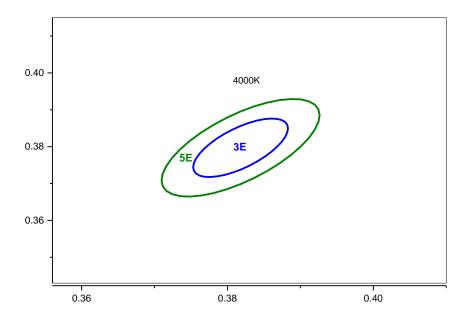
CIE Chromaticity Diagram (Cool White), T_j =85°C, I_F =700mA



6500	K 3Step	5700	K 3Step	5000K 3Step		
	3A		3B	3C		
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0066	Major Axis a	0.0072	Major Axis a	0.0081	
Minor Axis b	0.0027	Minor Axis b	0.0032	Minor Axis b	0.0035	
Ellipse	58	Ellipse	59	Ellipse	60	
Rotation Angle	56	Rotation Angle		Rotation Angle		
6500	K 5Step	5700	K 5Step	5000K 5Step		
	5A		5B		5 C	
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0110	Major Axis a	0.0119	Major Axis a	0.0135	
Minor Axis b	0.0045	Minor Axis b	0.0052	Minor Axis b	0.0059	
Ellipse	58	Ellipse	 59	Ellipse	60	
Rotation Angle	50	Rotation Angle		Rotation Angle		

Rev1.2 Nov. 2024 13 www.seoulsemicon.com

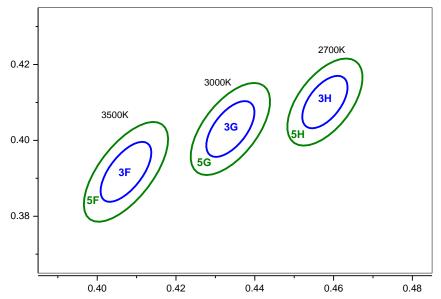
CIE Chromaticity Diagram (Neutral White), T_i=85°C, I_F=700mA



4000K 3Step 3E Center point 0.3818 : 0.3797 Major Axis a 0.0094 Minor Axis b 0.0041 Ellipse 53.4

4000K 5Step						
	5E					
Center point	0.3818 : 0.3797					
Major Axis a	0.0157					
Minor Axis b	0.0067					
Ellipse	53					
Rotation Angle						

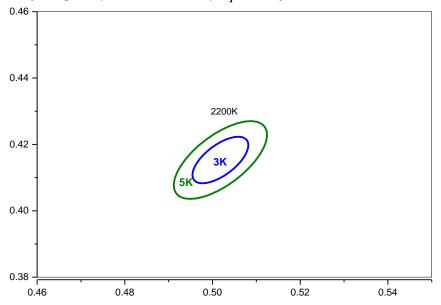
CIE Chromaticity Diagram (Warm White), T_j=85°C, I_F=700mA



	K 3Step 3F		K 3Step 3G	2700K 3Step 3H		
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101	
Major Axis a	0.0093	Major Axis a	0.0086	Major Axis a	0.0080	
Minor Axis b	0.0042	Minor Axis b	0.0042	Minor Axis b	0.0041	
Ellipse Rotation Angle	54	Ellipse Rotation Angle	54	Ellipse Rotation Angle	54	
3500	K 5Step	3000	K 5Step	2700K 5Step		
	5F		5 G		5H	
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101	
Major Axis a	0.0155	Major Axis a	0.0142	Major Axis a	0.0132	
Minor Axis b	0.0068	Minor Axis b	0.0068	Minor Axis b	0.0068	
Ellipse Rotation Angle	54	Ellipse Rotation Angle	54	Ellipse Rotation Angle	54	

Rev1.2 Nov. 2024 15 www.seoulsemicon.com

CIE Chromaticity Diagram (Soft Warm White), T_i=85°C, I_F=700mA



2200K 3Step					
3K					
Center point	0.5018 : 0.4153				
Major Axis a	0.0086				
Minor Axis b	0.0040				
Ellipse Rotation Angle	49.3				

2200K 55tep			
5K			
Center point	0.5018 : 0.4153		
Major Axis a	0.0144		
Minor Axis b	0.0066		
Ellipse Rotation Angle	49.3		



Mixing order kiting combination

Table 5 Kiting Combination with xx4M

Combination	Reel	FLUX	CIE	VF	Qty
Kiting_a	Reel 1	XXX	3S	290	900
	Reel 2	XXX	3S	290	900
Kiting_b	Reel 1	XXX	3S	290	900
	Reel 2	XXX	5S	290	900
Kiting_c	Reel 1	XXX	3S	290	900
	Reel 2	XXX	3S	300	900
Kiting_d	Reel 1	XXX	3S	290	900
	Reel 2	XXX	5S	300	900



Product Nomenclature

Table 6. Nomenclature example

Code digits	Value	References	Description
X ₁	S	Seoul Semiconductor	Company
X_2X_3	Z 5	Series	Z5 Series
X ₄	-	-	•
X ₅ X ₆	Mx	Chip Size	
X ₇	-	-	
X ₈ X ₉	Wx	ССТ	W0:5000K~6500K WN:4000K WW:2200K~3500K
X ₁₀	-	-	-
X ₁₁ X ₁₂	Сх	CRI	C7:CRI70 C8:CRI80 C9:CRI90
X ₁₃	-		-
X ₁₄ X ₁₅	Ex	Technology	
X ₁₆ X ₁₇	Ax	PCB	A3:AL2O3 AN:ALN
X ₁₈ X ₁₉ X ₂₀	000	Internalcode	
X ₂₁ X ₂₂ X ₂₃	abc	Flux (Min)	XXX
X ₂₄ X ₂₅	dd	ССТ	65=6500K, 57=5700K, 50=5000K,40=4000K, 30=3000K, 27= 2700K,22=2200K
X ₂₆ X ₂₇	ee	Step	3S-3step single /5S: 5step single / 4M: 4step Mixing
X ₂₈ X ₂₉ X ₃₀	fff	VF Bin(Max)	xxx

Rev1.2 Nov. 2024 18 www.seoulsemicon.com



Product Nomenclature

Table 7. Product Selection Table

Reference P/N	Order code	Flux bin (Min)	ССТ	Step	VF bin (Max)
	xxx65xS290	xxx:340	65:6500K		
SZ5-M4-W0-C7-E1AN000	xxx57xS290	xxx:340	57:5700K		
	xxx50xS290	xxx:340	50:5000K		
SZ5-M4-WN-C7-E1AN000	xxx40xS290	xxx:340	40:4000K		
	xxx35xS290	xxx:340	35:3500K		
SZ5-M4-WW-C7-E1AN000	xxx30xS290	xxx:325	30:3000K		
525-W4-WW-C7-ETAN000	xxx27xS290	xxx:310	27:2700K		
	xxx22xS290	xxx:280	22:2200K		
	xxx65xS290	xxx:325	65:6500K		290
SZ5-M4-W0-C8-E1AN000	xxx57xS290	xxx:325	57:5700K	3S: 3step single 5S: 5step single	
	xxx50xS290	xxx:325	50:5000K		
SZ5-M4-WN-C8-E1AN000	xxx40xS290	xxx:325	40:4000K		
	xxx35xS290	xxx:310	35:3500K		
SZ5-M4-WW-C8-E1AN000	xxx30xS290	xxx:295	30:3000K		
	xxx27xS290	xxx:280	27:2700K		
SZ5-M4-W0-C9-E1AN000	xxx65xS290	xxx:280	65:6500K		
	xxx57xS290	xxx:280	57:5700K		
	xxx50xS290	xxx:280	50:5000K		
SZ5-M4-WN-C9-E1AN000	xxx40xS290	xxx:280	40:4000K		
	xxx35xS290	xxx:265	35:3500K		
SZ5-M4-WW-C9-E1AN000	xxx30xS290	xxx:250	30:3000K		
	xxx27xS290	xxx:235	27:2700K		

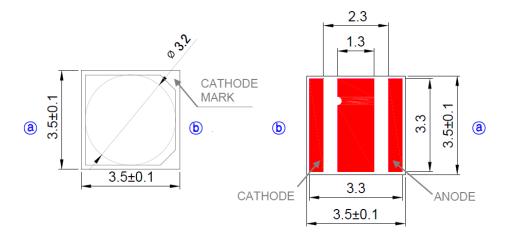


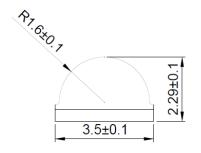
Product Nomenclature

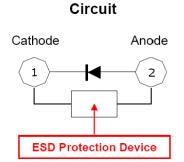
Table 8. Product Selection Table

Reference P/N	Order code	Flux bin (Min)	сст	Step	VF bin (Max)
	xxx654Mxxx	xxx:340	65:6500K		ALL
SZ5-M4-W0-C7-E1AN000	xxx574Mxxx	xxx:340	57:5700K		
	xxx504Mxxx	xxx:340	50:5000K		
SZ5-M4-WN-C7-E1AN000	xxx404Mxxx	xxx:340	40:4000K		
	xxx354Mxxx	xxx:340	35:3500K		
SZ5-M4-WW-C7-E1AN000	xxx304Mxxx	xxx:325	30:3000K		
525-M4-WW-C7-E1AN000	xxx274Mxxx	xxx:310	27:2700K		
	xxx224Mxxx	xxx:280	22:2200K		
	xxx654Mxxx	xxx:325	65:6500K		
SZ5-M4-W0-C8-E1AN000	xxx574Mxxx	xxx:325	57:5700K	- 4M: 4step Mixing	
	xxx504Mxxx	xxx:325	50:5000K		
SZ5-M4-WN-C8-E1AN000	xxx404Mxxx	xxx:325	40:4000K		
	xxx354Mxxx	xxx:310	35:3500K		
SZ5-M4-WW-C8-E1AN000	xxx304Mxxx	xxx:295	30:3000K		
	xxx274Mxxx	xxx:280	27:2700K		
	xxx654Mxxx	xxx:280	65:6500K		
SZ5-M4-W0-C9-E1AN000	xxx574Mxxx	xxx:280	57:5700K]	
	xxx504Mxxx	xxx:280	50:5000K		
SZ5-M4-WN-C9-E1AN000	xxx404Mxxx	xxx:280	40:4000K		
	xxx354Mxxx	xxx:265	35:3500K		
SZ5-M4-WW-C9-E1AN000	xxx304Mxxx	xxx:250	30:3000K		
	xxx274Mxxx	xxx:235	27:2700K		

Mechanical Dimensions





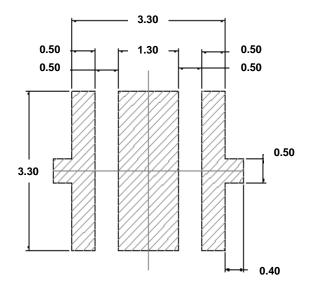


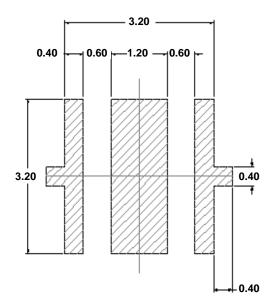
(1) All dimensions are in millimeters.

(2) Scale: none

(3) Undefined tolerance is $\pm 0.1 \text{mm}$

Recommended Solder Pad





Recommended PCB Solder Pad

Recommended Stencil Pattern

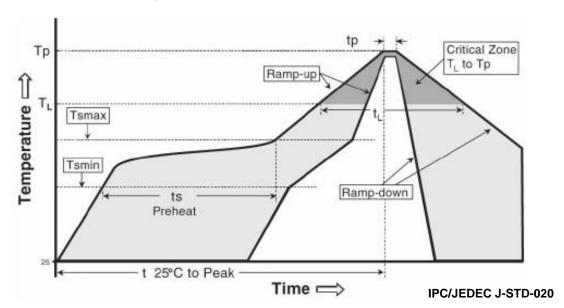
(1) All dimensions are in millimeters.

(2) Scale: none

(3) This drawing without tolerances are for reference only.

(4) Undefined tolerance is ± 0.1 mm.

Reflow Soldering Characteristics



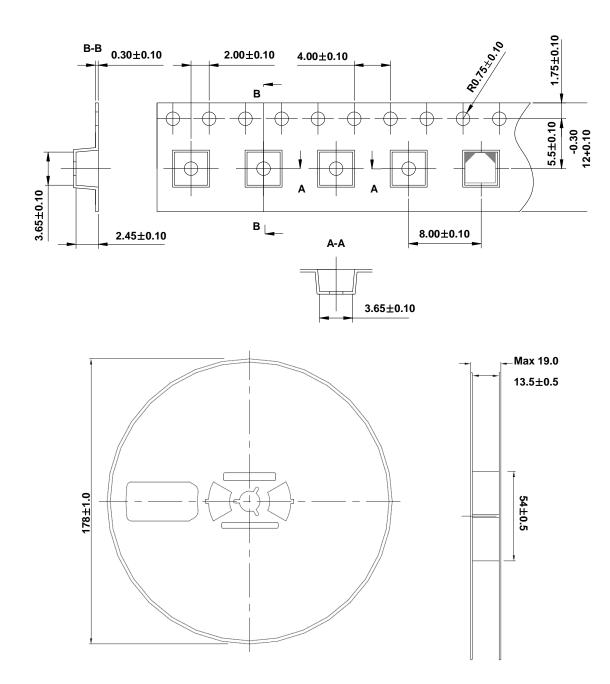
Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3° C/second max.	3° C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-180 seconds
Time maintained above: - Temperature (TL) - Time (tL)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak Temperature (Tp)	215°C	260°C
Time within 5°C of actual Peak Temperature (tp)2	10-30 seconds	20-40 seconds
Ramp-down Rate	6 °C/second max.	6 °C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LEDs will be damaged.
- (2) Repairs should not be done after the LEDs have been soldered. When repair is unavoidable, suitable tools must be used.
- (3) Die slug is to be soldered.
- (4) When soldering, do not put stress on the LEDs during heating.
- (5) After soldering, do not warp the circuit board.

Rev1.2 Nov. 2024 23 www.seoulsemicon.com

Emitter Tape & Reel Packaging



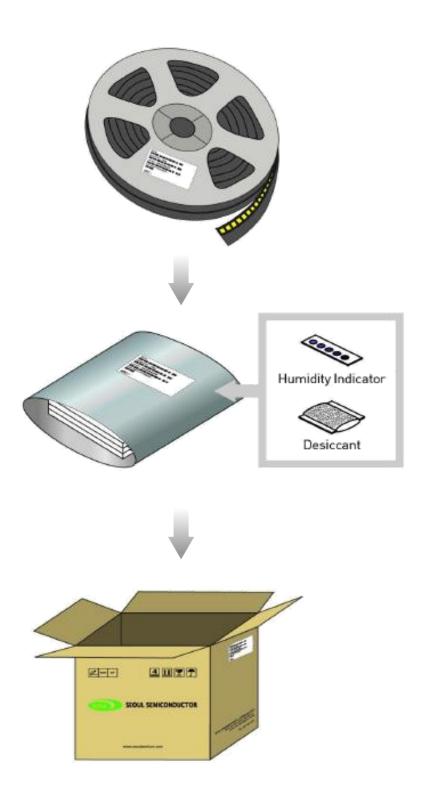
Notes:

UNIT: mm

- 1. Quantity: 900pcs/Reel
- 2. Cumulative Tolerance : Cumulative Tolerance/10 pitches to be ± 0.2 mm
- 3. Adhesion Strength of Cover Tape: Adhesion strength to be 10-60g when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape
- 4. Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package

Rev1.2 Nov. 2024 24 www.seoulsemicon.com

Packaging Information

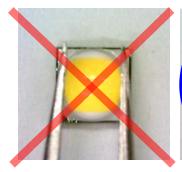


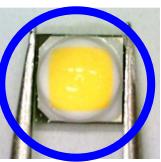


Handling of Silicone Resin for LEDs

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.







- (2) In general, LED should only be handled from the side. By the way, this also applies to LED without a silicone sealant, since the surface can also become scratched.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is larger than the LED's reflector area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LEDs. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing. In cases where a minimal level of dirt and dust particles cannot be guaranteed, a suitable cleaning solution must be applied to the surface after the soldering of components.
- (5) Seoul Semiconductor suggests using isopropyl alcohol for cleaning. In case other solvents are used, it must be assured that these solvents do not dissolve the package or resin. Ultrasonic cleaning is not recommended. Ultrasonic cleaning may cause damage to the LED.
- (6) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (7) Avoid leaving fingerprints on silicone resin parts.

Rev1.2 Nov. 2024 26 www.seoulsemicon.com



Precaution for Use

(1) Storage

To avoid the moisture penetration, we recommend storing LED in a dry box with a desiccant. The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use SMD techniques properly when solder the LED as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 30°C Humidity : less than RH60%
- b. If the package has been opened more than 4 weeks (MSL 2a) or the color of the desiccant changes, components should be dried for 10-24hr at $65\pm5^{\circ}$ C
- (3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.
- (4) Do not rapidly cool device after soldering.
- (5) Components should not be mounted on warped (non coplanar) portion of PCB.
- (6) Radioactive exposure is not considered for the products listed here in.
- (7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.
- (8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA (Isopropyl Alcohol) should be used.
- (9) When the LED are in operation the maximum current should be decided after measuring the package temperature.
- (10) The appearance and specifications of the product may be modified for improvement without notice.
- (11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

Rev1.2 Nov. 2024 27 www.seoulsemicon.com



Precaution for Use

- (12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures can penetrate silicone encapsulants of LED and discolor when exposed to heat and photonic energy. The result can be a significant loss of light output from the fixture. Knowledge of the properties of the materials selected to be used in the construction of fixtures can help prevent these issues.
- (13) Attaching LEDs, do not use adhesives that outgas organic vapor.
- (14) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the reverse voltage is applied to LED, migration can be generated resulting in LED damage.
- (15) LED is sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a list of suggestions that Seoul Semiconductor purposes to minimize these effects.
- a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LED may c ause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)

Rev1.2 Nov. 2024 28 www.seoulsemicon.com



Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package
 (If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)
- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- Damaged may be noticed to the bond wires (appearing similar to a blown fuse)
- Damage to the bond pads located on the emission surface of the LED package (shadowing can be noticed around the bond pads while viewing through a microscope)
- Anomalies noticed in the encapsulation and phosphor around the bond wires.
- This damage usually appears due to the thermal stress produced during the EOS event.
- c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:
 - A surge protection circuit
 - An appropriately rated over voltage protection device
 - A current limiting device

Rev1.2 Nov. 2024 29 www.seoulsemicon.com



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

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Rev1.2 Nov. 2024 30 www.seoulsemicon.com